



INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)

Atty. Docket No.: 99066CON (3600-198-02)

Application No.: 10/795,968

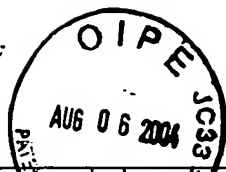
Applicant: HABECKER *et al.*

Filing Date: March 8, 2004

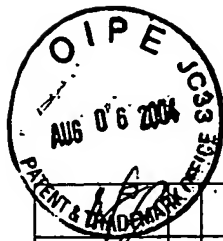
Group Art Unit: To Be Assigned

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Examiner Initial*	Document Number	Date	Name	Class	Sub Class	Filing Date If Appropriate
<i>g</i>	3,630,718	12/28/71	Neuenschwander	75	0.5	
	3,635,693	01/18/72	Friedrich et al.	75	0.5BB	
	3,647,420	03/07/72	Restelli	75	84	
	4,009,007	2/22/77	Fry	29	182.5	
	4,017,302	04/12/77	Bates et al.	75.5 BB	75/228	
	4,084,965	04/18/78	Fry	75	230	
	4,141,720	02/27/79	Vartanian	75	0.5BB	
	4,149,876	1/17/79	Rerat	75	0.5	
	4,231,790	11/04/80	Hahn et al.	75	0.5BB	
	4,347,084	08/31/82	Hahn et al.	75	245	
	4,356,028	10/26/82	Bates	75	0.5	
	4,441,927	4/10/84	Getz et al.	75	229	
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	4,512,805	04/23/85	Albrecht et al.	75	244	
	4,537,641	08/27/85	Albrecht et al.	148	11.5	
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	4,740,238	04/26/88	Schiele	75	0.5BB	
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		211,741	05/18/93	Fife	7	255	
		5,234,491	08/10/93	Chang	75	622	
		5,242,481	09/07/93	Kumar	75	364	
		5,245,514	09/14/93	Fife et al.	361	529	
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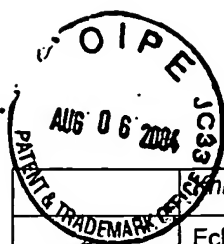
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	WO 00/08662 A1	2/17/00	WIPO	H01G	9/042	Yes
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Examiner <i>[Signature]</i>		Date Considered <i>3/28/05</i>	
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